



# N-Channel 30-V (D-S) MOSFET

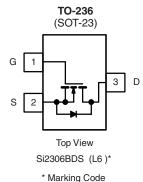
PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ.)		
30	$0.047$ at $V_{GS} = 10 \text{ V}$	4.0	3.0		
	0.065 at V <sub>GS</sub> = 4.5 V	3.5	3.0		

#### **FEATURES**

- Halogen-free Option Available
- TrenchFET® Power MOSFET
- 100 % R<sub>g</sub> Tested







Marking Codo

Ordering Information: Si2306BDS-T1-E3 (Lead (Pb)-free) Si2306BDS-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T<sub>A</sub> = 25 °C, unless otherwise noted

Parameter

Symbol 5 s Steady Sta

Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	30		V
Gate-Source Voltage		V <sub>GS</sub>	± 20		
Continuous Drain Current (T <sub>.J</sub> = 150 °C) <sup>a, b</sup>	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	4.0	3.16	^
Continuous Diain Current (1 <sub>J</sub> = 150°C)	T <sub>A</sub> = 70 °C		3.5	2.7	
Pulsed Drain Current		I <sub>DM</sub>	20		А
Continuous Source Current (Diode Conduction) <sup>a, b</sup>		I <sub>S</sub>	1.04	0.62	I
Marinum Branch Brain at and h	T <sub>A</sub> = 25 °C	- P <sub>D</sub>	1.25	0.75	W
Maximum Power Dissipation <sup>a, b</sup>	T <sub>A</sub> = 70 °C		0.8	0.48	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mariana la Ambienta	t ≤ 5 s	- R <sub>thJA</sub>	80	100	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		130	166	
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	60	75	

#### Notes:

- a. Surface Mounted on FR4 board,  $t \le 5 \text{ s.}$
- b. Pulse width limited by maximum junction temperature.
- c. Surface Mounted on FR4 board.

For SPICE model information via the Worldwide Web: http://www.vishay.com/www/product/spice.htm

# Vishay Siliconix

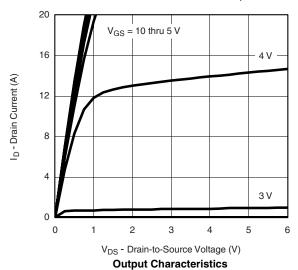


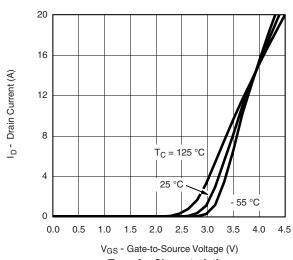
			Limits				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$				V	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0		3.0	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zara Cata Valtaga Drain Current	lasa	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			0.5	μΑ	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			10		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 4.5 \text{ V}, V_{GS} = 10 \text{ V}$	6			Α	
Durin Course On Braintana a	B	$V_{GS} = 10 \text{ V}, I_D = 3.5 \text{ A}$		0.038	0.047	Ω	
Drain-Source On-Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 2.8 \text{ A}$		0.052	0.065		
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	$V_{DS} = 4.5 \text{ V}, I_{D} = 2.5 \text{ A}$		7.0		S	
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> = 1.25 A, V <sub>GS</sub> = 0 V		0.8	1.2	V	
Dynamic							
Gate Charge	$Q_g$	$V_{DS} = 15 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 2.5 \text{ A}$		3.0	4.5	nC	
Total Gate Charge	Q <sub>gt</sub>			6	9		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 2.5 \text{ A}$		1.6			
Gate-Drain Charge	$Q_{gd}$			0.6			
Gate Resistance R		f = 1.0 MHz	2.5	5	7.5	Ω	
Input Capacitance	C <sub>iss</sub>			305			
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		65		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			29			
Switching			•	•			
Turn-On Delay Time	t <sub>d(on)</sub>			7	11		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 15 V, $R_L$ = 15 $\Omega$		12	18		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$		14	25	ns	
Fall Time	t <sub>f</sub>			6	10		
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 1.25 A, di/dt = 100 A/μs		14	21		
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	1 <sub>F</sub> = 1.25 A, αι/αι = 100 A/μS		6	10	nC	

#### Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





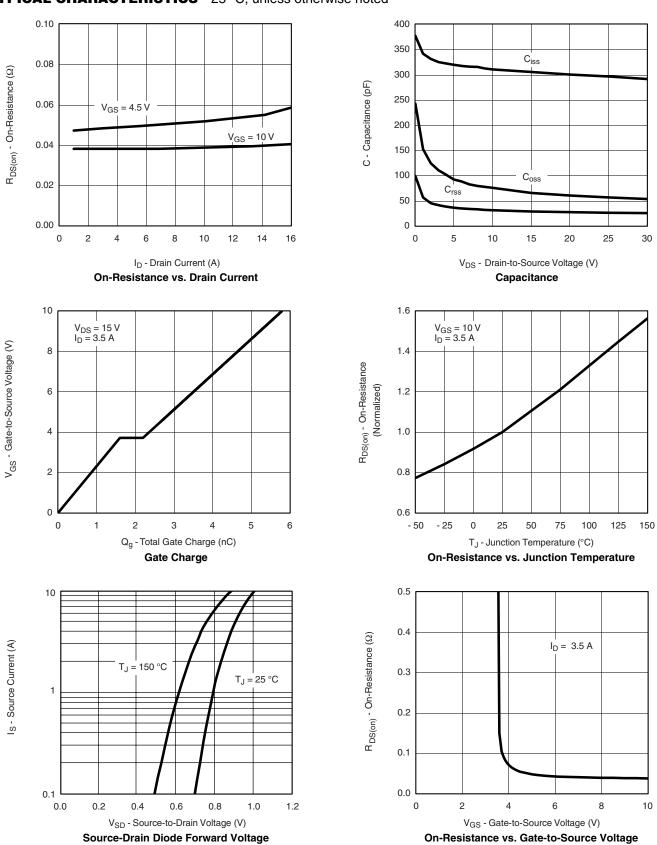
a. Pulse test: Pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.







#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



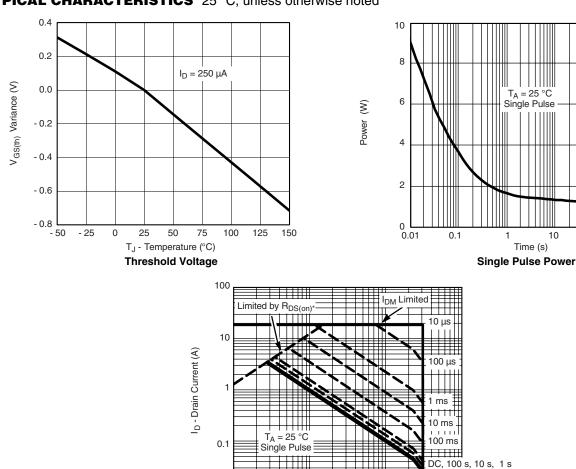
## Vishay Siliconix

# VISHAY

100

600

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



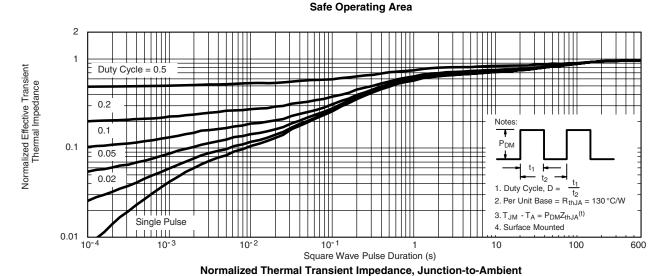
0.01 L 0.1

 $$V_{DS}$$  - Drain-to-Source Voltage (V)  $^*\,V_{GS}\,$  > minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

 $\mathsf{BV}_{\mathsf{DSS}}$  Limited

10

100



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